

# SANYO Semiconductors **DATA SHEET**

An ON Semiconductor Company

# STK760-213A-E — Single-phase rectification Active Converter Hybrid IC

#### Overview

This IC is average current control type Active Converter Hybrid IC for power factor improvement of single-phase AC power supply, that containing power devices of step-up active converter, control IC over-current and over-voltage protection circuits.

#### **Applications**

• Single-phase rectification active filter for power rectification for air conditioners and general-purpose inverters.

#### **Features**

- Power switching device for active converter is adopting IGBT.
- Soft start functions and the over current, the over voltage, and the low-voltage are including as protection circuit
- Capable of controlling ON/OFF by logic level input signal.
- Output voltage changeability functions by control signal.

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#### STK760-213A-E

# **Specifications**

# **Absolute Maximum Ratings** at Ta = 25°C

	Parameter		Symbol	Conditions		Ratings	unit
IGBT	Collector-emitter voltage		VCE			600	V
(TR1+TR2)	Repetitive peak collector current		ICP		*1	300	Α
	Collector current		IC			105	Α
ĺ	Power dissipation		PC1			156	W
FRD1	Diode reverse voltage		VRM			600	V
(D1)	Repetitive peak forward current		IF1P		*1	110	Α
	Diode forward current		IF1			36	Α
	Power dissipation		PD1			75	W
FRD2	Repetitive peak forward current		IF2P		*1	15	Α
(D2)	Diode forward current		IF2			7	Α
	Power dissipation		PD2			13	W
Supply volta	ge (V <sub>CC</sub> -GND)		V <sub>CC</sub>			20	V
Signal pin input voltage         Pin 4           Pin 5         Pin 8           Pin 9         Pin 2           Pin 6         Maximum input AC voltage		VIS			-10 to 0.3		
		VCOMP					
		VFB			-0.3 to 6.5	V	
		VOVP					
		VONF					
		Vctl			-0.3 to V <sub>CC</sub>		
		VAC	Single-phase Full-rectified		264	V	
Maximum ou	ıtput voltage		VO	Under the Application condition		450	V
Maximum ou	itput power		Wo	(VAC=200V)		6	kW
Input AC current (normal condition)  Junction temperature		I <sub>IN</sub>			30	Arms	
		Tj			150	°C	
Operating case temperature		Тс	HIC case temperature	*2	-20 to +100	°C	
Storage temperature		Tstg			-40 to +125	°C	
Tightening torque			A screw part	*3	1.17	N•m	
Withstand voltage			VINS	50Hz sine wave AC 1minute	*4	2000	VRMS

#### [Note]

- \*1: Duty ratio D = 0.1, tp = 1ms
- \*2: Measure point is between 5mm to center of back.
- \*3: Torque should be set within 0.79 to 1.17N·m. Flatness of the heat-sink should be lower than 0.2mm.
- \*4: The test condition: AC2500V, 1 second.

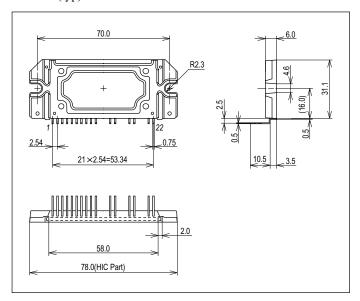
# STK760-213A-E

# **Electrical Characteristics** at Tc = 25°C, $V_{CC} = 15.0$ V: Unless otherwise noted

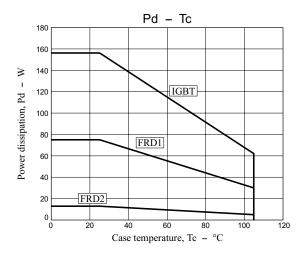
Demonstra	0	O and difference	Test circuit	Ratings			
Parameter	Symbol	Conditions		min	typ	max	unit
Power output part							
Collector-emitter leak current (IGBT)	ICES	V <sub>CE</sub> = 600V	Fig.1			200	μА
Collector-emitter saturation voltage (IGBT)	V <sub>CE</sub> (sat)	I <sub>C</sub> = 40A	Fig.2		1.2	1.8	V
Diode reverse current (FRD1)	IR	V <sub>R</sub> = 600V	Fig.1			200	μА
Diode forward voltage (FRD1)	V <sub>F</sub> 1	I <sub>F</sub> = 40A	Fig.3		2.2	2.8	V
Diode forward voltage (FRD2)	V <sub>F</sub> 2	I <sub>F</sub> = 5A	Fig.3		2.5	3.5	٧
Junction to case thermal resistance	θј-с1	IGBT (TR1+TR2)			0.80		°C/W
	θј-с2	FRD1 (D1)			1.65		°C/W
	θј-с3	FRD2 (D2)			9.0		°C/W
Control IC part	1				,		
Control IC input current	I <sub>CC</sub> (ON)	V <sub>CC</sub> = 15V, VONF = 5V			14	20	mA
	I <sub>CC</sub> (OFF)	V <sub>CC</sub> = 15V, VONF = 0V			2.5	5	
Oscillation frequency	fosc	V <sub>CC</sub> = 15V, VONF = 5V	Fig.4	19.5	22.0	24.5	kHz
Open loop protection threshold voltage	VOLP			0.8	0.95	1.1	V
Error-amp reference voltage	Vref	-		4.88	5.0	5.12	V
Peak current protection threshold voltage	VIS(PK)		Fig.5	-0.58	-0.5	-0.42	V
Over voltage protection threshold voltage	VOVP(ON)		Fig.6	5.095	5.3	5.51	V
ON/OFF threshold voltage	VTHON	V <sub>CC</sub> = 15V	Fig.7	3.0			٧
	VTHOFF					0.5	V
Start-up V <sub>CC</sub> voltage	V <sub>CC</sub> (ON)	VONF = 5V		12.4	13.25	14.1	٧
Shut-down V <sub>CC</sub> voltage	V <sub>CC</sub> (OFF)	1	Fig.8	9.4	10.0	10.7	V
Substrate temperature monitor resistance	RTH	Resistance between VTH-GND	Fig.3	90	100	110	kΩ
Application circuit : VAC = 200V, VO =	= 380V (Vctl = 1.5	507V)	· '		<u>'</u>		
Output voltage	V <sub>O</sub>	Wo = 2kW		366	380	394	V
Power Factor	cosφ	Wo = 400W	Fig.9	0.98	0.99		
		Wo = 2kW	1 1	0.99	0.995	1.0	

# **Package Dimensions**

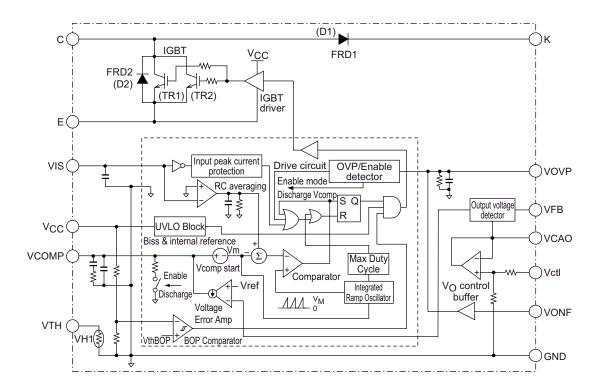
unit:mm (typ)



# IGBT (TR1+TR2), FRD1 (D1) & FRD2 (D2) vs. Temperature Derating (Ta = $25^{\circ}$ C)



#### **Block Diagram**



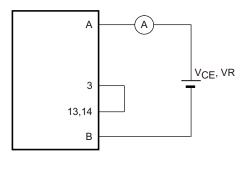
# **Explanation of Terminal**

Terminal No.	Symbol	Explanation	
1	Vcc	Control IC power supply input	
2	VONF	ON/OFF control terminal	
3	GND	Signal GND	
4	VIS	Current detection terminal	
5	VCOMP	Phase compensation terminal (Voltage error amplifier out)	
6	VctI	Output voltage control signal input	
7	VCAO	Output voltage control amplifier output	
8	VFB	Output voltage feed back terminal	
9	VOVP	Over voltage protection terminal	
10	VTH	Terminal of thermistor TH1	
11, 12	-	An empty terminal	
13, 14	E	IGBT (TR1+TR2) Emitter	
15, 16	-	An empty terminal	
17, 18	С	IGBT (TR1+TR2) Collector	
19, 20	-	An empty terminal	
21, 22	К	FRD1 (D1) Cathode	

# **Test Circuit -1**

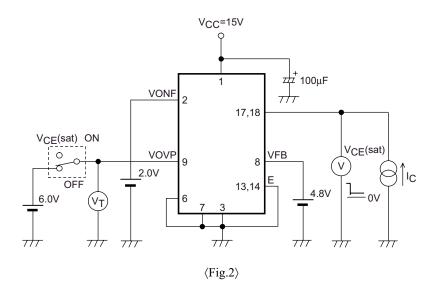
#### (1) ICES, IR

	IGBT	FRD1
Α	17, 18	21, 22
В	13, 14	17, 18



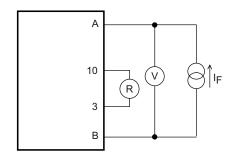
 $\langle Fig.1 \rangle$ 

#### (2) V<sub>CE</sub>(sat) (Test by Pulse)



#### (3) $V_F1$ , $V_F2$ (Test by Pulse), RTH

	FRD1	FRD2
Α	17, 18	13, 14
В	21, 22	17, 18

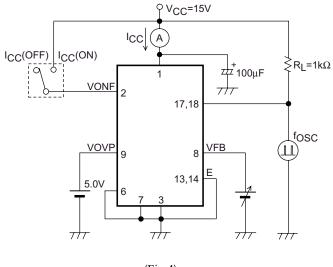


 $\langle Fig.3 \rangle$ 

#### **Test Circuit -2**

#### (4) ICC(ON)/ICC(OFF), VOLP, fOSC

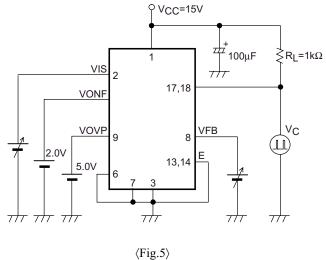
Icc, fosc	VOLP
VFB = 1.1V	VONF = 5.0V



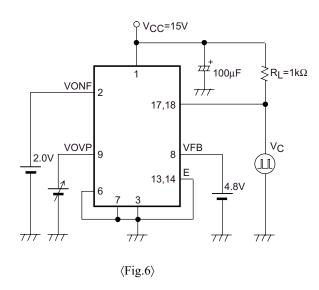
 $\langle Fig.4 \rangle$ 

#### (5) Vref, VIS(PK)

Vref	VIS(PK)	
VIS = -0.6V	VFB = 4.8V	

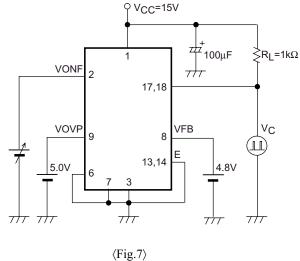


#### (6) VOVP(ON)



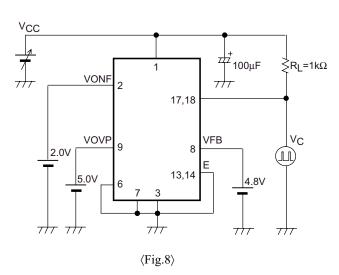
#### **Test Circuit -3**

#### (7) VTHON, VTHOFF

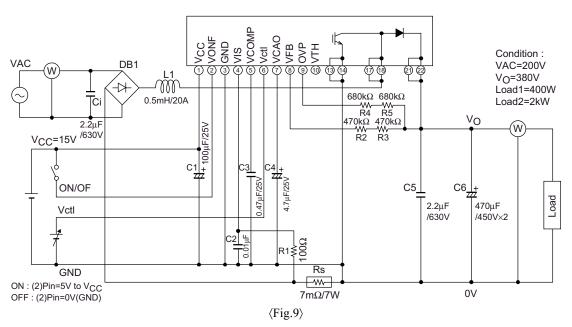


#### (8) V<sub>CC</sub>(ON), V<sub>CC</sub>(OFF)

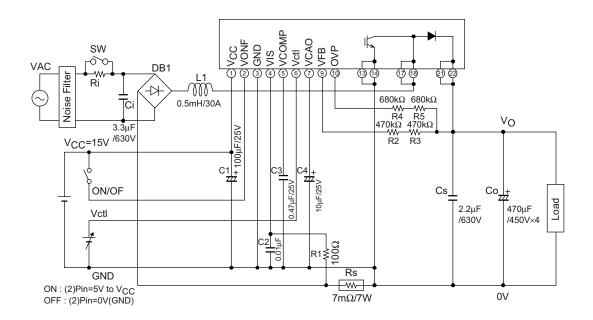
V <sub>CC</sub> (ON)	V <sub>CC</sub> (OFF)
Vc-ON	Vc-OFF



#### (9) Power Factor (COS\$\phi\$)



#### **Application Circuit**

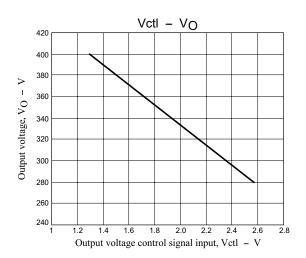


#### **Recommended Condition**

Parameter	Symbol	Conditions	Ratings	unit
AC Voltage	VAC	50/60Hz	170 to 264	Vrms
Output voltage	VO		VAC×√2+(10 to 15)≤450	V
Over-voltage detection voltage	VOV		V <sub>OUT</sub> +(10 to 20)	V
Control IC supply voltage	V <sub>CC</sub>	V <sub>CC</sub> -GND	14.5 to 17.0	V
Inductor	L1		0.5	mH
Input film capacitor	Ci		3.3≤Ci	μF
Output film capacitor	Cs		2.2≤Cs	μF
Output electrolytic capacitor	Со		1880≤Co	μF

#### **Output Voltage Control**

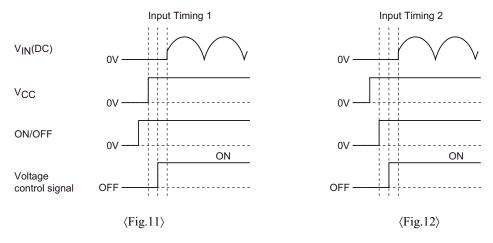
Output voltage control signal Vctl sets referring to the Vctl-VO characteristic of the figure below.



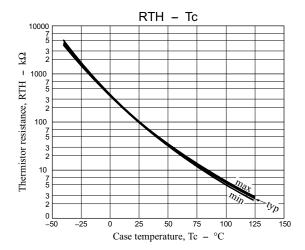
#### **Timing Chart**

Even if power supply and signal at any timing are input, this IC is not destroyed. However, soft start circuit doesn't operate when  $V_{IN}(DC)$  is input at the timing of Figure 11 and 12. Therefore, overcurrent protection circuit will operate, and audio frequency noise from coil may generate.

Please turn on ON/OFF or  $V_{\mbox{\footnotesize{CC}}}$  after  $V_{\mbox{\footnotesize{IN}}}(\mbox{\footnotesize{DC}})$  to avoid this.



#### The built-in thermistor resistance temperature characteristic



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